

# PNP EPITAXIAL SILICON TRANSISTOR

### **Features**

- Excellent HFE Linearity HFE
- hFE(2)=25(Min.) at VCE=6V ,lc=400m
- High Total Power Dissipation: Pc=225mW
- · RoHS compliant package

### **Mechanical Data**

- · Case: SOT-23 Molded plastic
- · Epoxy: UL94V-O rate flame retardant

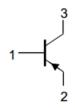
### **Packing & Order Information**

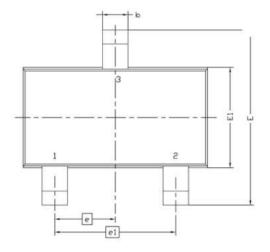
3,000/Reel

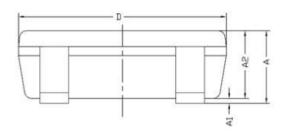


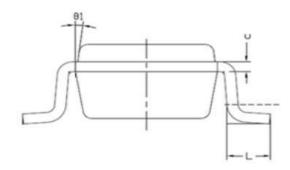
RoHS COMPLIANT

### **Graphic symbol**









Cumbal	MILLIMETERS		
Symbol	MIN	MAX	
Α	0.8	1.2	
A1	0	0.1	
A2	0.7	1.1	
b	0.3	0.5	
С	0.1	0.2	
D	2.7	3.1	
E	2.6	3	
E1	1.4	1.8	
е	0.95 BSC		
e1	1.9 BSC		
L	0.3	0.6	
θ1	7° NOM		



# PNP EPITAXIAL SILICON TRANSISTOR

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

MAXIMUM	MAXIMUM RATINGS (Ta=25°C unless otherwise noted)				
Symbol	Parameter	S9012	Unit		
$V_{CBO}$	Collector-Base Voltage	-40	Vdc		
$V_{CEO}$	Collector-Emitter Voltage	-30	Vdc		
$V_{EBO}$	Emitter-Base Voltage	-5	Vdc		
I <sub>C</sub>	Collector Current	-500	mAdc		
P <sub>D</sub>	Collector Power Dissipation	300	mW		
Tj,Tstg	Junction and Storage Temperature	-55 to +150	°C		

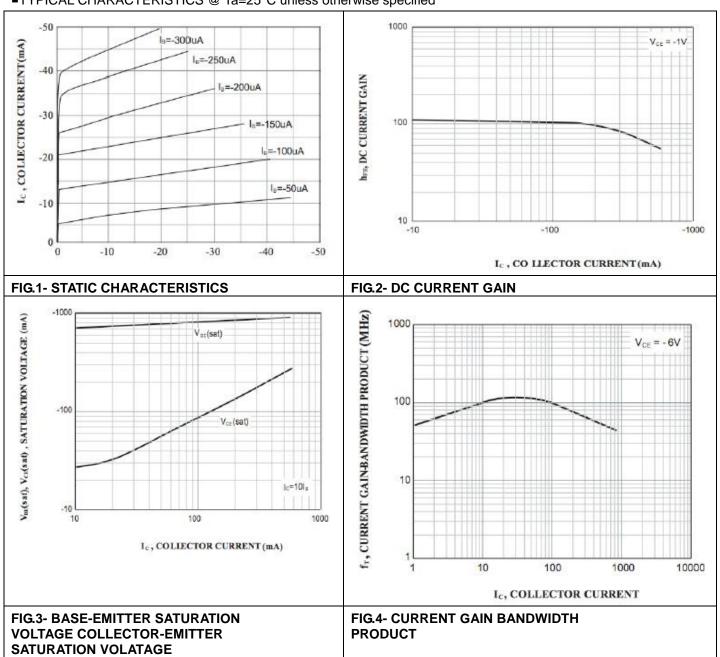
ELECTRIC	ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified						
Symbol	Parameter	Test Conditions	MIN	TYP	MAX	UNIT	
$V_{(BR)CBO} \\$	Collector-base breakdown voltage	$I_{C} = -100 \mu A$	-40			V	
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C = -1 \text{ mA}$	-30			V	
$V_{(BR)EBO}$	Emitter-base breakdown voltage	I <sub>E</sub> = -100μA	-5			V	
I <sub>CBO</sub>	Collector cut-off current	$V_{CB} = -35 \text{ V}, I_{E} = 0$			-0.1	uA	
I <sub>EBO</sub>	Emitter cut-off current	$V_{EB} = -5 \text{ V}, I_{C} = 0$			-0.1	uA	
h <sub>FE(1)</sub>	DC current gain	$V_{CE} = -1 \text{ V}$ , $I_{C} = -100 \text{ mA}$	70		400		
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_C = -500 \text{ mA}$ , $I_B = -50 \text{ mA}$			-0.6	V	
$V_{BE}$	Base-Emitter Saturation Voltage	$V_{CE} = -1 \text{ V, } I_{C} = -100 \text{mA}$		-0.8	-1.0	V	
f <sub>T</sub>	Transition frequency	$V_{CE} = -6 \text{ V}$ , $I_{C} = -20 \text{ mA}$	150	300		MHz	
C <sub>ob</sub>	Collector output capacitance	$V_{CB} = -6 \text{ V}, I_{E} = 0$ f = 1.0MHz		7	10	pF	

CLASSIFICATION OF h <sub>FE</sub>				
Rank	L	Н		
Rang	70-200	200-400		



# PNP EPITAXIAL SILICON TRANSISTOR

■TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified





## PNP EPITAXIAL SILICON TRANSISTOR

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE. Bruckewell Technology Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Bruckewell"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product. Bruckewell makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Bruckewell disclaims

- (i) Any and all liability arising out of the application or use of any product.
- (ii) Any and all liability, including without limitation special, consequential or incidental damages.
- (iii) Any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Bruckewell's knowledge of typical requirements that are often placed on Bruckewell products in generic applications.

Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time.

Product specifications do not expand or otherwise modify Bruckewell's terms and conditions of purchase, including but not limited to the warranty expressed therein.